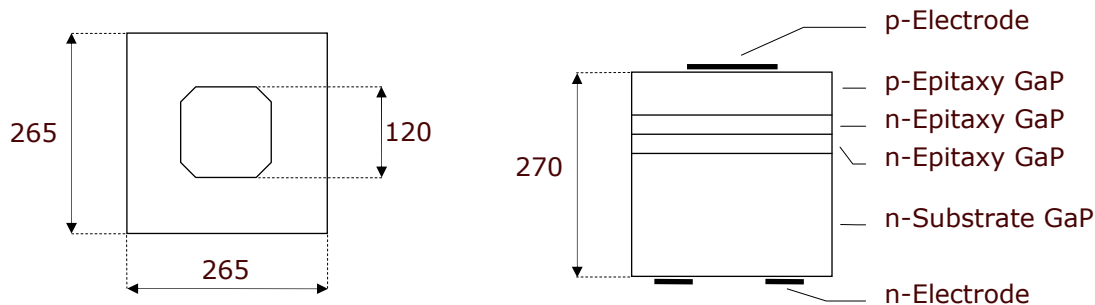


<b>YELLOW-GREEN</b>	<b>Item No.: 160260</b>
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1. This specification applies to GaP / GaP LED Chips
2. Structure
  - 2.1 Mesa structure
  - 2.2 Electrodes
 

p-side (anode)	Au alloy
n-side (cathode)	Au alloy
3. Outlines (dimensions in microns)



Wire bond contacts can also be circular or square

4. Electrical and optical characteristics (T=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Forward voltage	$V_F$	$I_F = 20 \text{ mA}$		2,25	2,50	V
Reverse current	$I_R$	$V_R = 5 \text{ V}$			10	$\mu\text{A}$
Luminous intensity *	$I_V$	$I_F = 20 \text{ mA}$	13,0	16,5		mcd
Peak wavelength	$\lambda_P$	$I_F = 20 \text{ mA}$		568		nm

\* On request, wafers will be delivered according to luminous intensity classes  
Brightness measurement at OSA on gold plate

5. Packing
  - 1) wire bond side on top
  - 2) back contact on top

6. Labeling

Type	Lot No.	$I_V$ typ min max	Quantity
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